NSN 5962-01-272-7303

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-272-7303 **Body Length:** 32.0 millimeters **Body Width:** 13.4 millimeters **Body Height:** 5.3 millimeters **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -55.0/+125.0 degrees celsius **End Application:** 6740-01-058-8710 titler, aerial r **Features Provided:** High speed and low power and w/enable and bidirectional **Inclosure Material:** Plastic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 22 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig:

A458a0

Demilitarization: Yes - demil/mli